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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR 2SK3899

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK3899 is N-channel MOS Field Effect Transistor designed for high current switching applications.

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3899-ZK	TO-263 (MP-25ZK)

FEATURES

• Super low on-state resistance

 $R_{DS(on)1}$ = 5.3 m Ω MAX. (Vgs = 10 V, ID = 42 A)

 $R_{DS(on)2} = 6.5 \text{ m}\Omega \text{ MAX.} \text{ (Vgs} = 4.5 \text{ V, I}_D = 42 \text{ A)}$

- Low Ciss: Ciss = 5500 pF TYP.
- Built-in gate protection diode

(TO-263)



ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C)

Drain to Source Voltage (V _{GS} = 0 V)	VDSS	60	V
Gate to Source Voltage (V _{DS} = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	ID(DC)	±84	Α
Drain Current (pulse) Note1	D(pulse)	±336	Α
Total Power Dissipation (Tc = 25°C)	P _{T1}	146	W
Total Power Dissipation (T _A = 25°C)	P _{T2}	1.5	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Energy Note2	Eas	245	mJ
Repetitive Avalanche Current Note3	lar	49.5	Α
Repetitive Avalanche Energy Note3	Ear	245	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

- **2.** Starting T_{ch} = 25°C, V_{DD} = 30 V, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V, L = 100 μ H
- 3. Rg = 25 Ω , Tch(peak) \leq 150°C

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90%



ELECTRICAL CHARACTERISTICS (TA = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 60 V, V _{GS} = 0 V			10	μΑ
Gate Leakage Current	Igss	V _{GS} = ±20 V, V _{DS} = 0 V			±10	μΑ
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.5	2.0	2.5	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = 10 V, I _D = 42 A	35	70		S
Drain to Source On-state Resistance Note	RDS(on)1	V _{GS} = 10 V, I _D = 42 A		4.2	5.3	mΩ
	RDS(on)2	V _{GS} = 4.5 V, I _D = 42 A		4.9	6.5	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V		5500		pF
Output Capacitance	Coss	V _{GS} = 0 V		1050		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		350		pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 30 V, I _D = 42 A		19		ns
Rise Time	t r	V _{GS} = 10 V		13		ns
Turn-off Delay Time	td(off)	$R_G = 0 \Omega$		91		ns
Fall Time	tf			10		ns
Total Gate Charge	Q _G	V _{DD} = 48 V		96		nC
Gate to Source Charge	Q _G s	V _{GS} = 10 V		18		nC
Gate to Drain Charge	Q _{GD}	I _D = 84 A		23.5		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	I _F = 84 A, V _{GS} = 0 V		0.92	1.5	V
Reverse Recovery Time	trr	I _F = 84 A, V _{GS} = 0 V		49		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		70		nC

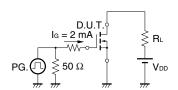
Note Pulsed

TEST CIRCUIT 1 AVALANCHE CAPABILITY

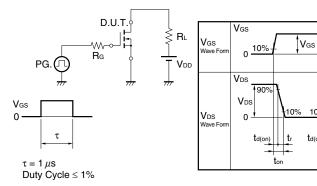
$V_{GS} = 20 \rightarrow 0 \text{ V}$ $V_{GS} = 20 \rightarrow 0 \text{ V}$ V_{DD} V_{DD} V_{DD} V_{DD} V_{DD} V_{DD} V_{DD}

Starting Tch

TEST CIRCUIT 3 GATE CHARGE



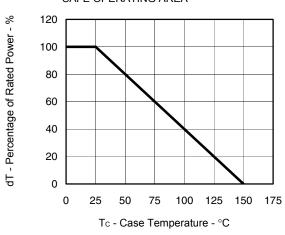
TEST CIRCUIT 2 SWITCHING TIME



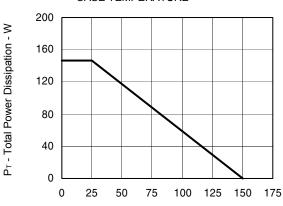


TYPICAL CHARACTERISTICS (TA = 25°C)

DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA

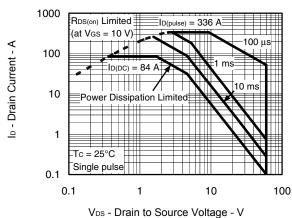


TOTAL POWER DISSIPATION vs. CASE TEMPERATURE

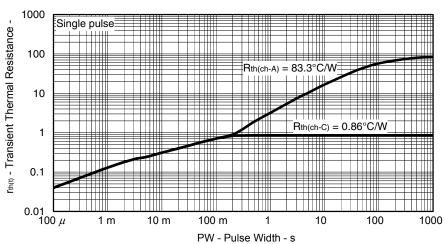


Tc - Case Temperature - °C

FORWARD BIAS SAFE OPERATING AREA



TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



0

VGS(off) - Gate Cut-off Voltage - V

0

1

V₋₁ 300 V_{GS} = 10 V 4.5 V 4.5 V

DRAIN CURRENT vs.

VDS - Drain to Source Voltage - V

3

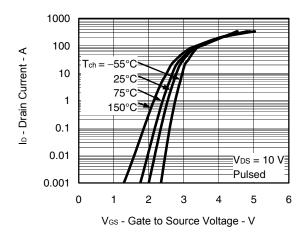
2

Pulsed

5

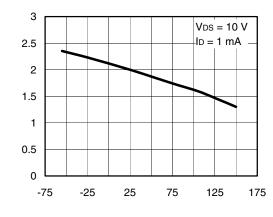
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FORWARD TRANSFER CHARACTERISTICS



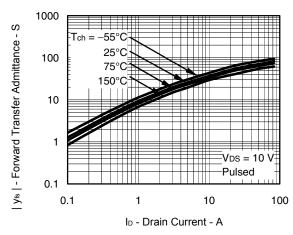
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GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE

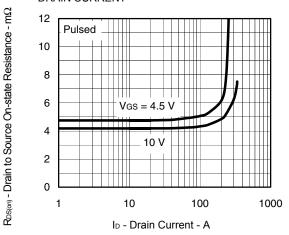


Tch - Channel Temperature - °C

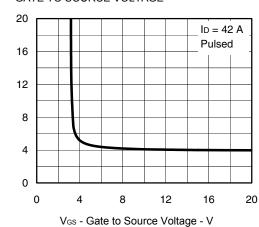
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

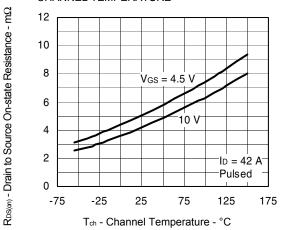


RDS(on) - Drain to Source On-state Resistance - m\Omega

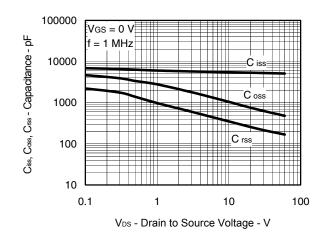
td(on), tr, td(off), tr - Switching Time - ns

IF - Diode Forward Current - A

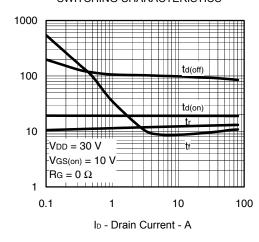
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



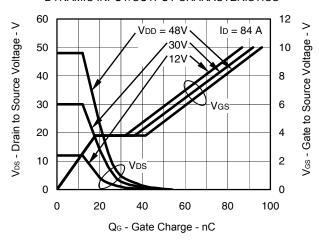
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



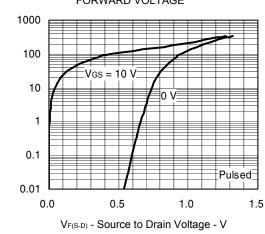
SWITCHING CHARACTERISTICS



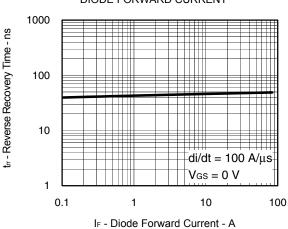
DYNAMIC INPUT/OUTPUT CHARACTERISTICS

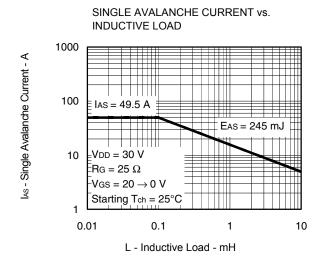


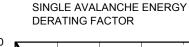
SOURCE TO DRAIN DIODE FORWARD VOLTAGE

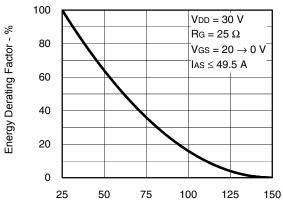


REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT







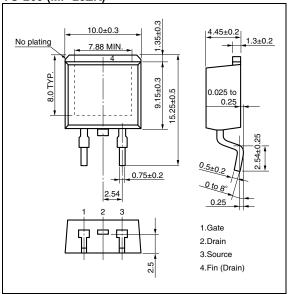


Starting Tch - Starting Channel Temperature - °C

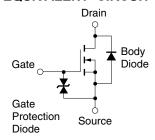


PACKAGE DRAWING (Unit: mm)

TO-263 (MP-25ZK)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

Data Sheet D17174EJ1V0DS 7

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